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### Understanding **Embedded - FPGAs (Field Programmable Gate Array)**

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### Details

Product Status	Obsolete
Number of LABs/CLBs	4548
Number of Logic Elements/Cells	90960
Total RAM Bits	4520488
Number of I/O	758
Number of Gates	-
Voltage - Supply	1.15V ~ 1.25V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	1020-BBGA
Supplier Device Package	1020-FBGA (33x33)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/intel/ep2s90f1020c4">https://www.e-xfl.com/product-detail/intel/ep2s90f1020c4</a>



# Section I. Stratix II Device Family Data Sheet

This section provides the data sheet specifications for Stratix® II devices. This section contains feature definitions of the internal architecture, configuration and JTAG boundary-scan testing information, DC operating conditions, AC timing parameters, a reference to power consumption, and ordering information for Stratix II devices.

This section contains the following chapters:

- [Chapter 1, Introduction](#)
- [Chapter 2, Stratix II Architecture](#)
- [Chapter 3, Configuration & Testing](#)
- [Chapter 4, Hot Socketing & Power-On Reset](#)
- [Chapter 5, DC & Switching Characteristics](#)
- [Chapter 6, Reference & Ordering Information](#)

## Revision History

Refer to each chapter for its own specific revision history. For information on when each chapter was updated, refer to the Chapter Revision Dates section, which appears in the full handbook.

Stratix II devices are available in space-saving FineLine BGA® packages (see [Tables 1–2](#) and [1–3](#)).

**Table 1–2. Stratix II Package Options & I/O Pin Counts** *Notes (1), (2)*

Device	484-Pin FineLine BGA	484-Pin Hybrid FineLine BGA	672-Pin FineLine BGA	780-Pin FineLine BGA	1,020-Pin FineLine BGA	1,508-Pin FineLine BGA
EP2S15	342		366			
EP2S30	342		500			
EP2S60 (3)	334		492		718	
EP2S90 (3)		308		534	758	902
EP2S130 (3)				534	742	1,126
EP2S180 (3)					742	1,170

**Notes to Table 1–2:**

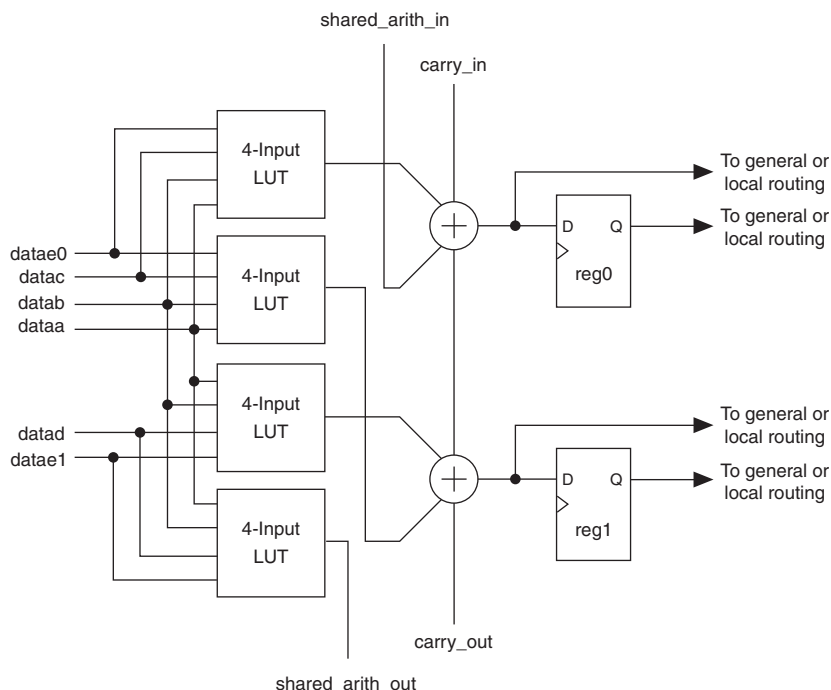
- (1) All I/O pin counts include eight dedicated clock input pins (clk1p, clk1n, clk3p, clk3n, clk9p, clk9n, clk11p, and clk11n) that can be used for data inputs.
- (2) The Quartus II software I/O pin counts include one additional pin, PLL\_ENA, which is not available as general-purpose I/O pins. The PLL\_ENA pin can only be used to enable the PLLs within the device.
- (3) The I/O pin counts for the EP2S60, EP2S90, EP2S130, and EP2S180 devices in the 1020-pin and 1508-pin packages include eight dedicated fast PLL clock inputs (FPLL7CLKp/n, FPLL8CLKp/n, FPLL9CLKp/n, and FPLL10CLKp/n) that can be used for data inputs.

**Table 1–3. Stratix II FineLine BGA Package Sizes**

Dimension	484 Pin	484-Pin Hybrid	672 Pin	780 Pin	1,020 Pin	1,508 Pin
Pitch (mm)	1.00	1.00	1.00	1.00	1.00	1.00
Area (mm <sup>2</sup> )	529	729	729	841	1,089	1,600
Length × width (mm × mm)	23 × 23	27 × 27	27 × 27	29 × 29	33 × 33	40 × 40

All Stratix II devices support vertical migration within the same package (for example, you can migrate between the EP2S15, EP2S30, and EP2S60 devices in the 672-pin FineLine BGA package). Vertical migration means that you can migrate to devices whose dedicated pins, configuration pins, and power pins are the same for a given package across device densities.

To ensure that a board layout supports migratable densities within one package offering, enable the applicable vertical migration path within the Quartus II software (Assignments menu > Device > Migration Devices).

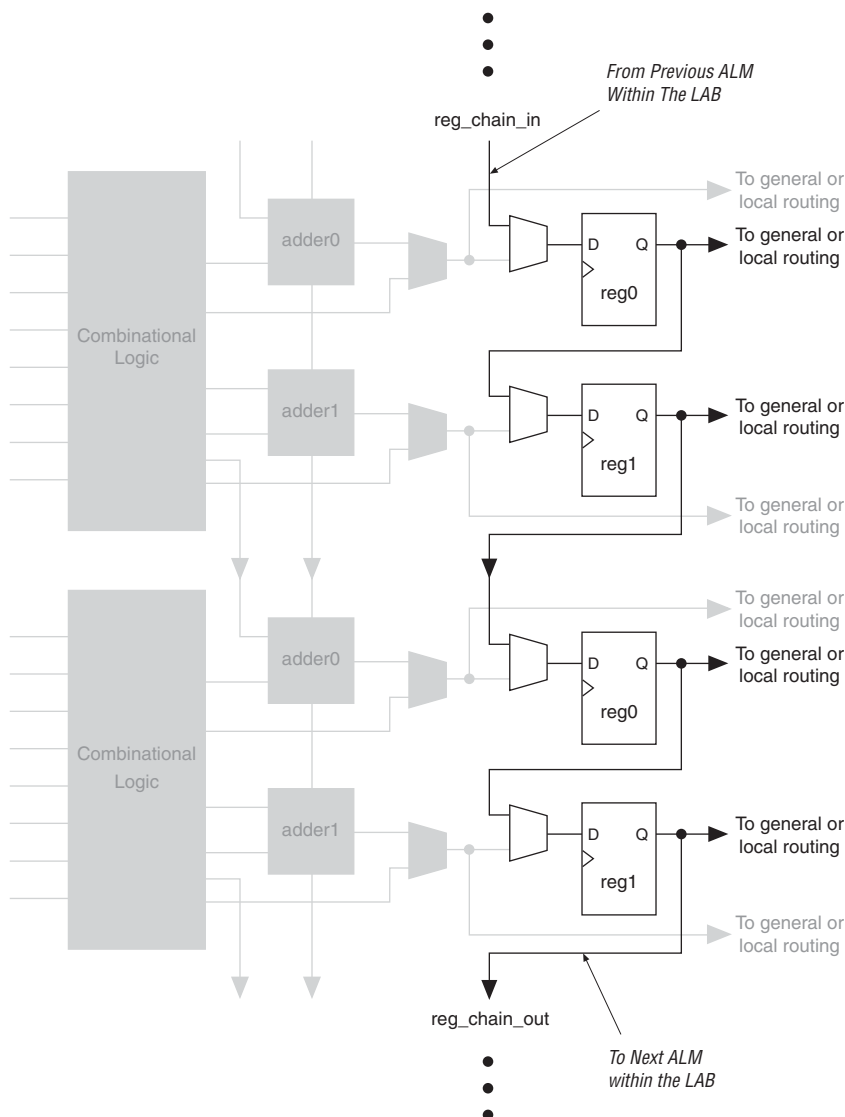
**Figure 2–13. ALM in Shared Arithmetic Mode****Note to Figure 2–13:**

- (1) Inputs dataae0 and datae1 are available for register packing in shared arithmetic mode.

Adder trees can be found in many different applications. For example, the summation of the partial products in a logic-based multiplier can be implemented in a tree structure. Another example is a correlator function that can use a large adder tree to sum filtered data samples in a given time frame to recover or to de-spread data which was transmitted utilizing spread spectrum technology.

An example of a three-bit add operation utilizing the shared arithmetic mode is shown in Figure 2–14. The partial sum ( $S[2..0]$ ) and the partial carry ( $C[2..0]$ ) is obtained using the LUTs, while the result ( $R[2..0]$ ) is computed using the dedicated adders.

**Figure 2–15. Register Chain within an LAB** *Note (1)*



**Note to Figure 2–15:**

(1) The combinational or adder logic can be utilized to implement an unrelated, un-registered function.

See the “MultiTrack Interconnect” on page 2–22 section for more information on register chain interconnect.

## PLLs & Clock Networks

Stratix II devices provide a hierarchical clock structure and multiple PLLs with advanced features. The large number of clocking resources in combination with the clock synthesis precision provided by enhanced and fast PLLs provides a complete clock management solution.

### Global & Hierarchical Clocking

Stratix II devices provide 16 dedicated global clock networks and 32 regional clock networks (eight per device quadrant). These clocks are organized into a hierarchical clock structure that allows for up to 24 clocks per device region with low skew and delay. This hierarchical clocking scheme provides up to 48 unique clock domains in Stratix II devices.

There are 16 dedicated clock pins ( $\text{CLK}[15..0]$ ) to drive either the global or regional clock networks. Four clock pins drive each side of the device, as shown in [Figures 2–31](#) and [2–32](#). Internal logic and enhanced and fast PLL outputs can also drive the global and regional clock networks. Each global and regional clock has a clock control block, which controls the selection of the clock source and dynamically enables/disables the clock to reduce power consumption. [Table 2–8](#) shows global and regional clock features.

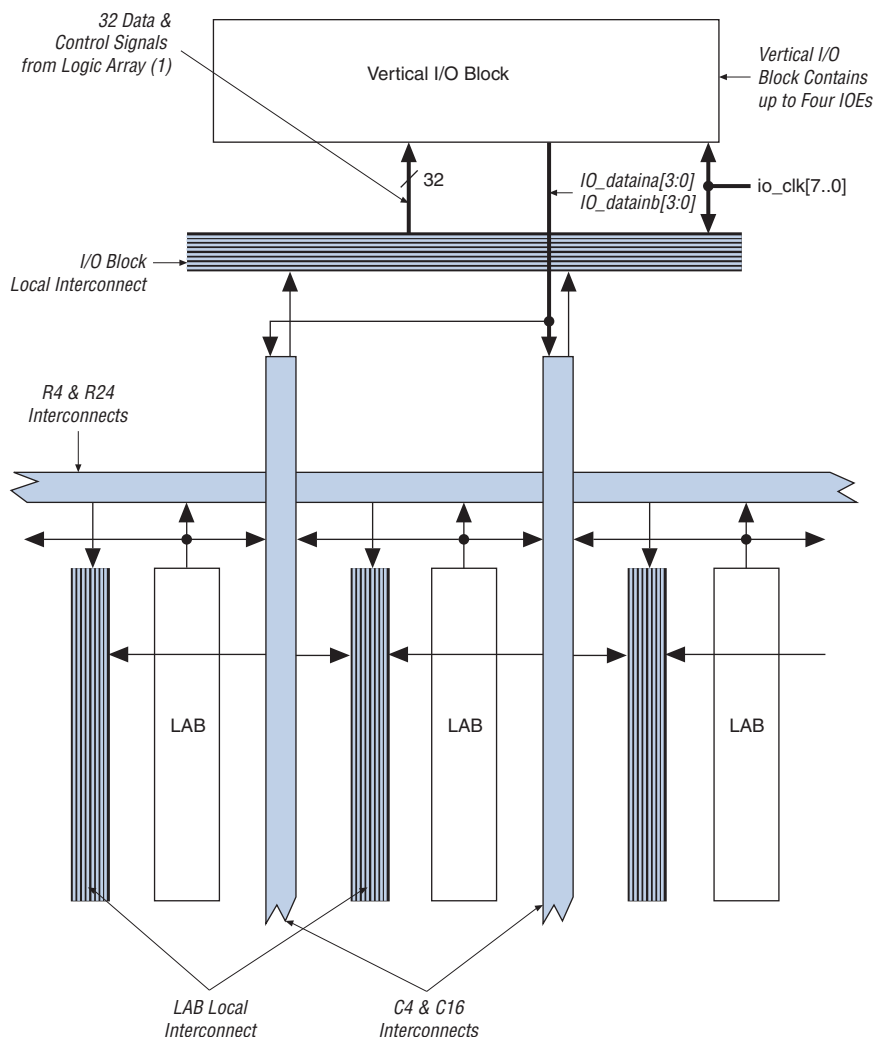
<b>Table 2–8. Global &amp; Regional Clock Features</b>		
<b>Feature</b>	<b>Global Clocks</b>	<b>Regional Clocks</b>
Number per device	16	32
Number available per quadrant	16	8
Sources	CLK pins, PLL outputs, or internal logic	CLK pins, PLL outputs, or internal logic
Dynamic clock source selection	✓ (1)	
Dynamic enable/disable	✓	✓

**Note to [Table 2–8](#):**

- (1) Dynamic source clock selection is supported for selecting between CLKp pins and PLL outputs only.

### Global Clock Network

These clocks drive throughout the entire device, feeding all device quadrants. The global clock networks can be used as clock sources for all resources in the device-IOEs, ALMs, DSP blocks, and all memory blocks. These resources can also be used for control signals, such as clock enables and synchronous or asynchronous clears fed from the external pin. The

**Figure 2–48. Column I/O Block Connection to the Interconnect** *Note (1)***Note to Figure 2–48:**

- (1) The 32 data and control signals consist of eight data out lines: four lines each for DDR applications  $io\_dataouta[3..0]$  and  $io\_dataoutb[3..0]$ , four output enables  $io\_oe[3..0]$ , four input clock enables  $io\_ce\_in[3..0]$ , four output clock enables  $io\_ce\_out[3..0]$ , four clocks  $io\_clk[3..0]$ , four asynchronous clear and preset signals  $io\_aclr/apreset[3..0]$ , and four synchronous clear and preset signals  $io\_sclr/spreset[3..0]$ .

The Stratix II device IOE includes programmable delays that can be activated to ensure input IOE register-to-logic array register transfers, input pin-to-logic array register transfers, or output IOE register-to-pin transfers.

A path in which a pin directly drives a register may require the delay to ensure zero hold time, whereas a path in which a pin drives a register through combinational logic may not require the delay. Programmable delays exist for decreasing input-pin-to-logic-array and IOE input register delays. The Quartus II Compiler can program these delays to automatically minimize setup time while providing a zero hold time. Programmable delays can increase the register-to-pin delays for output and/or output enable registers. Programmable delays are no longer required to ensure zero hold times for logic array register-to-IOE register transfers. The Quartus II Compiler can create the zero hold time for these transfers. Table 2–13 shows the programmable delays for Stratix II devices.

**Table 2–13. Stratix II Programmable Delay Chain**

Programmable Delays	Quartus II Logic Option
Input pin to logic array delay	Input delay from pin to internal cells
Input pin to input register delay	Input delay from pin to input register
Output pin delay	Delay from output register to output pin
Output enable register $t_{CO}$ delay	Delay to output enable pin

The IOE registers in Stratix II devices share the same source for clear or preset. You can program preset or clear for each individual IOE. You can also program the registers to power up high or low after configuration is complete. If programmed to power up low, an asynchronous clear can control the registers. If programmed to power up high, an asynchronous preset can control the registers. This feature prevents the inadvertent activation of another device's active-low input upon power-up. If one register in an IOE uses a preset or clear signal then all registers in the IOE must use that same signal if they require preset or clear. Additionally, a synchronous reset signal is available for the IOE registers.

## Double Data Rate I/O Pins

Stratix II devices have six registers in the IOE, which support DDR interfacing by clocking data on both positive and negative clock edges. The IOEs in Stratix II devices support DDR inputs, DDR outputs, and bidirectional DDR modes.



The bus-hold circuitry also pulls undriven pins away from the input threshold voltage where noise can cause unintended high-frequency switching. You can select this feature individually for each I/O pin. The bus-hold output drives no higher than  $V_{CCIO}$  to prevent overdriving signals. If the bus-hold feature is enabled, the programmable pull-up option cannot be used. Disable the bus-hold feature when the I/O pin has been configured for differential signals.

The bus-hold circuitry uses a resistor with a nominal resistance ( $R_{BH}$ ) of approximately 7 k $\Omega$  to weakly pull the signal level to the last-driven state. See the *DC & Switching Characteristics* chapter in the *Stratix II Device Handbook, Volume 1*, for the specific sustaining current driven through this resistor and overdrive current used to identify the next-driven input level. This information is provided for each  $V_{CCIO}$  voltage level.

The bus-hold circuitry is active only after configuration. When going into user mode, the bus-hold circuit captures the value on the pin present at the end of configuration.

## Programmable Pull-Up Resistor

Each Stratix II device I/O pin provides an optional programmable pull-up resistor during user mode. If you enable this feature for an I/O pin, the pull-up resistor (typically 25 k $\Omega$ ) weakly holds the output to the  $V_{CCIO}$  level of the output pin's bank.

Programmable pull-up resistors are only supported on user I/O pins, and are not supported on dedicated configuration pins, JTAG pins or dedicated clock pins.

## Advanced I/O Standard Support

Stratix II device IOEs support the following I/O standards:

- 3.3-V LVTTL/LVCMOS
- 2.5-V LVTTL/LVCMOS
- 1.8-V LVTTL/LVCMOS
- 1.5-V LVCMOS
- 3.3-V PCI
- 3.3-V PCI-X mode 1
- LVDS
- LVPECL (on input and output clocks only)
- HyperTransport technology
- Differential 1.5-V HSTL Class I and II
- Differential 1.8-V HSTL Class I and II
- Differential SSTL-18 Class I and II
- Differential SSTL-2 Class I and II

**Table 2–17. On-Chip Termination Support by I/O Banks (Part 2 of 2)**

On-Chip Termination Support	I/O Standard Support	Top & Bottom Banks	Left & Right Banks
Series termination with calibration	3.3-V LVTTTL	✓	
	3.3-V LVCMOS	✓	
	2.5-V LVTTTL	✓	
	2.5-V LVCMOS	✓	
	1.8-V LVTTTL	✓	
	1.8-V LVCMOS	✓	
	1.5-V LVTTTL	✓	
	1.5-V LVCMOS	✓	
	SSTL-2 Class I and II	✓	
	SSTL-18 Class I and II	✓	
	1.8-V HSTL Class I	✓	
	1.8-V HSTL Class II	✓	
	1.5-V HSTL Class I	✓	
	1.2-V HSTL	✓	
Parallel termination with calibration	SSTL-2 Class I and II	✓	
	SSTL-18 Class I and II	✓	
	1.8-V HSTL Class I	✓	
	1.8-V HSTL Class II	✓	
	1.5-V HSTL Class I and II	✓	
	1.2-V HSTL	✓	
Differential termination (1)	LVDS		✓
	HyperTransport technology		✓

**Note to Table 2–17:**

- (1) Clock pins CLK1, CLK3, CLK9, CLK11, and pins FPLL[7..10] CLK do not support differential on-chip termination. Clock pins CLK0, CLK2, CLK8, and CLK10 do support differential on-chip termination. Clock pins in the top and bottom banks (CLK[4..7, 12..15]) do not support differential on-chip termination.

**Table 2–20. Supported TDO/TDI Voltage Combinations (Part 2 of 2)**

Device	TDI Input Buffer Power	Stratix II TDO $V_{CCIO}$ Voltage Level in I/O Bank 4				
		$V_{CCIO} = 3.3\text{ V}$	$V_{CCIO} = 2.5\text{ V}$	$V_{CCIO} = 1.8\text{ V}$	$V_{CCIO} = 1.5\text{ V}$	$V_{CCIO} = 1.2\text{ V}$
Non-Stratix II	VCC = 3.3 V	✓ (1)	✓ (2)	✓ (3)	Level shifter required	Level shifter required
	VCC = 2.5 V	✓ (1), (4)	✓ (2)	✓ (3)	Level shifter required	Level shifter required
	VCC = 1.8 V	✓ (1), (4)	✓ (2), (5)	✓	Level shifter required	Level shifter required
	VCC = 1.5 V	✓ (1), (4)	✓ (2), (5)	✓ (6)	✓	✓

**Notes to Table 2–20:**

- (1) The TDO output buffer meets  $V_{OH}(\text{MIN}) = 2.4\text{ V}$ .
- (2) The TDO output buffer meets  $V_{OH}(\text{MIN}) = 2.0\text{ V}$ .
- (3) An external  $250\text{-}\Omega$  pull-up resistor is not required, but recommended if signal levels on the board are not optimal.
- (4) Input buffer must be 3.3-V tolerant.
- (5) Input buffer must be 2.5-V tolerant.
- (6) Input buffer must be 1.8-V tolerant.

## High-Speed Differential I/O with DPA Support

Stratix II devices contain dedicated circuitry for supporting differential standards at speeds up to 1 Gbps. The LVDS and HyperTransport differential I/O standards are supported in the Stratix II device. In addition, the LVPECL I/O standard is supported on input and output clock pins on the top and bottom I/O banks.

The high-speed differential I/O circuitry supports the following high speed I/O interconnect standards and applications:

- SPI-4 Phase 2 (POS-PHY Level 4)
- SFI-4
- Parallel RapidIO
- HyperTransport technology

There are four dedicated high-speed PLLs in the EP2S15 to EP2S30 devices and eight dedicated high-speed PLLs in the EP2S60 to EP2S180 devices to multiply reference clocks and drive high-speed differential SERDES channels.

Tables 2–21 through 2–26 show the number of channels that each fast PLL can clock in each of the Stratix II devices. In Tables 2–21 through 2–26 the first row for each transmitter or receiver provides the number of channels driven directly by the PLL. The second row below it shows the maximum channels a PLL can drive if cross bank channels are used from the adjacent center PLL. For example, in the 484-pin FineLine BGA EP2S15



An encryption configuration file is the same size as a non-encryption configuration file. When using a serial configuration scheme such as passive serial (PS) or active serial (AS), configuration time is the same whether or not the design security feature is enabled. If the fast passive parallel (FPP) scheme is used with the design security or decompression feature, a  $4 \times$  DCLK is required. This results in a slower configuration time when compared to the configuration time of an FPGA that has neither the design security, nor decompression feature enabled. For more information about this feature, refer to *AN 341: Using the Design Security Feature in Stratix II Devices*. Contact your local Altera sales representative to request this document.

### *Device Configuration Data Decompression*

Stratix II FPGAs support decompression of configuration data, which saves configuration memory space and time. This feature allows you to store compressed configuration data in configuration devices or other memory, and transmit this compressed bit stream to Stratix II FPGAs. During configuration, the Stratix II FPGA decompresses the bit stream in real time and programs its SRAM cells.

Stratix II FPGAs support decompression in the FPP (when using a MAX II device/microprocessor and flash memory), AS and PS configuration schemes. Decompression is not supported in the PPA configuration scheme nor in JTAG-based configuration.

### *Remote System Upgrades*

Shortened design cycles, evolving standards, and system deployments in remote locations are difficult challenges faced by modern system designers. Stratix II devices can help effectively deal with these challenges with their inherent re-programmability and dedicated circuitry to perform remote system updates. Remote system updates help deliver feature enhancements and bug fixes without costly recalls, reduce time to market, and extend product life.

Stratix II FPGAs feature dedicated remote system upgrade circuitry to facilitate remote system updates. Soft logic (Nios® processor or user logic) implemented in the Stratix II device can download a new configuration image from a remote location, store it in configuration memory, and direct the dedicated remote system upgrade circuitry to initiate a reconfiguration cycle. The dedicated circuitry performs error detection during and after the configuration process, recovers from any error condition by reverting back to a safe configuration image, and provides

**Table 5–3. Stratix II Device Recommended Operating Conditions (Part 2 of 2)** *Note (1)*

Symbol	Parameter	Conditions	Minimum	Maximum	Unit
$T_J$	Operating junction temperature	For commercial use	0	85	°C
		For industrial use	–40	100	°C
		For military use (7)	–55	125	°C

**Notes to Table 5–3:**

- (1) Supply voltage specifications apply to voltage readings taken at the device pins, not at the power supply.
- (2) During transitions, the inputs may overshoot to the voltage shown in Table 5–2 based upon the input duty cycle. The DC case is equivalent to 100% duty cycle. During transitions, the inputs may undershoot to –2.0 V for input currents less than 100 mA and periods shorter than 20 ns.
- (3) Maximum  $V_{CC}$  rise time is 100 ms, and  $V_{CC}$  must rise monotonically from ground to  $V_{CC}$ .
- (4)  $V_{CCPD}$  must ramp-up from 0 V to 3.3 V within 100  $\mu$ s to 100 ms. If  $V_{CCPD}$  is not ramped up within this specified time, your Stratix II device does not configure successfully. If your system does not allow for a  $V_{CCPD}$  ramp-up time of 100 ms or less, you must hold  $nCONFIG$  low until all power supplies are reliable.
- (5) All pins, including dedicated inputs, clock, I/O, and JTAG pins, may be driven before  $V_{CCINT}$ ,  $V_{CCPD}$ , and  $V_{CCIO}$  are powered.
- (6)  $V_{CCIO}$  maximum and minimum conditions for PCI and PCI-X are shown in parentheses.
- (7) For more information, refer to the *Stratix II Military Temperature Range Support* technical brief.

## DC Electrical Characteristics

Table 5–4 shows the Stratix II device family DC electrical characteristics.

**Table 5–4. Stratix II Device DC Operating Conditions (Part 1 of 2)** *Note (1)*

Symbol	Parameter	Conditions		Minimum	Typical	Maximum	Unit
$I_I$	Input pin leakage current	$V_I = V_{CCIOmax}$ to 0 V (2)		–10		10	$\mu$ A
$I_{OZ}$	Tri-stated I/O pin leakage current	$V_O = V_{CCIOmax}$ to 0 V (2)		–10		10	$\mu$ A
$I_{CCINT0}$	$V_{CCINT}$ supply current (standby)	$V_I$ = ground, no load, no toggling inputs $T_J = 25^\circ$ C	EP2S15		0.25	(3)	A
			EP2S30		0.30	(3)	A
			EP2S60		0.50	(3)	A
			EP2S90		0.62	(3)	A
			EP2S130		0.82	(3)	A
			EP2S180		1.12	(3)	A
$I_{CCPD0}$	$V_{CCPD}$ supply current (standby)	$V_I$ = ground, no load, no toggling inputs $T_J = 25^\circ$ C, $V_{CCPD} = 3.3$ V	EP2S15		2.2	(3)	mA
			EP2S30		2.7	(3)	mA
			EP2S60		3.6	(3)	mA
			EP2S90		4.3	(3)	mA
			EP2S130		5.4	(3)	mA
			EP2S180		6.8	(3)	mA

**Table 5–8. 1.8-V I/O Specifications**

Symbol	Parameter	Conditions	Minimum	Maximum	Unit
$V_{CCIO}$ (1)	Output supply voltage		1.71	1.89	V
$V_{IH}$	High-level input voltage		$0.65 \times V_{CCIO}$	2.25	V
$V_{IL}$	Low-level input voltage		–0.30	$0.35 \times V_{CCIO}$	V
$V_{OH}$	High-level output voltage	$I_{OH} = -2 \text{ mA}$ (2)	$V_{CCIO} - 0.45$		V
$V_{OL}$	Low-level output voltage	$I_{OL} = 2 \text{ mA}$ (2)		0.45	V

**Notes to Table 5–8:**

- (1) The Stratix II device family's  $V_{CCIO}$  voltage level support of  $1.8 \pm -5\%$  is narrower than defined in the Normal Range of the EIA/JEDEC standard.
- (2) This specification is supported across all the programmable drive settings available for this I/O standard as shown in the *Stratix II Architecture* chapter in volume 1 of the *Stratix II Device Handbook*.

**Table 5–9. 1.5-V I/O Specifications**

Symbol	Parameter	Conditions	Minimum	Maximum	Unit
$V_{CCIO}$ (1)	Output supply voltage		1.425	1.575	V
$V_{IH}$	High-level input voltage		$0.65 \times V_{CCIO}$	$V_{CCIO} + 0.30$	V
$V_{IL}$	Low-level input voltage		–0.30	$0.35 \times V_{CCIO}$	V
$V_{OH}$	High-level output voltage	$I_{OH} = -2 \text{ mA}$ (2)	$0.75 \times V_{CCIO}$		V
$V_{OL}$	Low-level output voltage	$I_{OL} = 2 \text{ mA}$ (2)		$0.25 \times V_{CCIO}$	V

**Notes to Table 5–9:**

- (1) The Stratix II device family's  $V_{CCIO}$  voltage level support of  $1.5 \pm -5\%$  is narrower than defined in the Normal Range of the EIA/JEDEC standard.
- (2) This specification is supported across all the programmable drive settings available for this I/O standard as shown in the *Stratix II Architecture* chapter in volume 1 of the *Stratix II Device Handbook*.

Figures 5–1 and 5–2 show receiver input and transmitter output waveforms, respectively, for all differential I/O standards (LVDS, LVPECL, and HyperTransport technology).

**Table 5–14. 3.3-V PCI Specifications (Part 2 of 2)**

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V <sub>IL</sub>	Low-level input voltage		–0.3		$0.3 \times V_{CCIO}$	V
V <sub>OH</sub>	High-level output voltage	I <sub>OUT</sub> = –500 µA	$0.9 \times V_{CCIO}$			V
V <sub>OL</sub>	Low-level output voltage	I <sub>OUT</sub> = 1,500 µA			$0.1 \times V_{CCIO}$	V

**Table 5–15. PCI-X Mode 1 Specifications**

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V <sub>CCIO</sub>	Output supply voltage		3.0		3.6	V
V <sub>IH</sub>	High-level input voltage		$0.5 \times V_{CCIO}$		$V_{CCIO} + 0.5$	V
V <sub>IL</sub>	Low-level input voltage		–0.30		$0.35 \times V_{CCIO}$	V
V <sub>IPU</sub>	Input pull-up voltage		$0.7 \times V_{CCIO}$			V
V <sub>OH</sub>	High-level output voltage	I <sub>OUT</sub> = –500 µA	$0.9 \times V_{CCIO}$			V
V <sub>OL</sub>	Low-level output voltage	I <sub>OUT</sub> = 1,500 µA			$0.1 \times V_{CCIO}$	V

**Table 5–16. SSTL-18 Class I Specifications**

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V <sub>CCIO</sub>	Output supply voltage		1.71	1.80	1.89	V
V <sub>REF</sub>	Reference voltage		0.855	0.900	0.945	V
V <sub>TT</sub>	Termination voltage		$V_{REF} - 0.04$	V <sub>REF</sub>	$V_{REF} + 0.04$	V
V <sub>IH</sub> (DC)	High-level DC input voltage		$V_{REF} + 0.125$			V
V <sub>IL</sub> (DC)	Low-level DC input voltage				$V_{REF} - 0.125$	V
V <sub>IH</sub> (AC)	High-level AC input voltage		$V_{REF} + 0.25$			V
V <sub>IL</sub> (AC)	Low-level AC input voltage				$V_{REF} - 0.25$	V
V <sub>OH</sub>	High-level output voltage	I <sub>OH</sub> = –6.7 mA (1)	$V_{TT} + 0.475$			V
V <sub>OL</sub>	Low-level output voltage	I <sub>OL</sub> = 6.7 mA (1)			$V_{TT} - 0.475$	V

**Note to Table 5–16:**

- (1) This specification is supported across all the programmable drive settings available for this I/O standard as shown in the *Stratix II Architecture* chapter in volume 1 of the *Stratix II Device Handbook*.

**Table 5–31. Series & Differential On-Chip Termination Specification for Left & Right I/O Banks**

Symbol	Description	Conditions	Resistance Tolerance		
			Commercial Max	Industrial Max	Unit
25-Ω $R_S$ 3.3/2.5	Internal series termination without calibration (25-Ω setting)	$V_{CCIO} = 3.3/2.5$ V	±30	±30	%
50-Ω $R_S$ 3.3/2.5/1.8	Internal series termination without calibration (50-Ω setting)	$V_{CCIO} = 3.3/2.5/1.8$ V	±30	±30	%
50-Ω $R_S$ 1.5	Internal series termination without calibration (50-Ω setting)	$V_{CCIO} = 1.5$ V	±36	±36	%
$R_D$	Internal differential termination for LVDS or HyperTransport technology (100-Ω setting)	$V_{CCIO} = 2.5$ V	±20	±25	%

## Pin Capacitance

Table 5–32 shows the Stratix II device family pin capacitance.

**Table 5–32. Stratix II Device Capacitance** *Note (1)*

Symbol	Parameter	Typical	Unit
$C_{IOTB}$	Input capacitance on I/O pins in I/O banks 3, 4, 7, and 8.	5.0	pF
$C_{IOLR}$	Input capacitance on I/O pins in I/O banks 1, 2, 5, and 6, including high-speed differential receiver and transmitter pins.	6.1	pF
$C_{CLKTB}$	Input capacitance on top/bottom clock input pins: CLK[4 . . 7] and CLK[12 . . 15].	6.0	pF
$C_{CLKLR}$	Input capacitance on left/right clock inputs: CLK0, CLK2, CLK8, CLK10.	6.1	pF
$C_{CLKLR+}$	Input capacitance on left/right clock inputs: CLK1, CLK3, CLK9, and CLK11.	3.3	pF
$C_{OUTFB}$	Input capacitance on dual-purpose clock output/feedback pins in PLL banks 9, 10, 11, and 12.	6.7	pF

**Note to Table 5–32:**

- (1) Capacitance is sample-tested only. Capacitance is measured using time-domain reflections (TDR). Measurement accuracy is within ±0.5pF



**Table 5–36. Stratix II Performance Notes (Part 3 of 6)** *Note (1)*

Applications		Resources Used			Performance				
		ALUTs	TriMatrix Memory Blocks	DSP Blocks	-3 Speed Grade (2)	-3 Speed Grade (3)	-4 Speed Grade	-5 Speed Grade	Unit
DSP block	9 × 9-bit multiplier (5)	0	0	1	430.29	409.16	373.13	320.10	MHz
	18 × 18-bit multiplier (5)	0	0	1	410.17	390.01	356.12	305.06	MHz
	18 × 18-bit multiplier (7)	0	0	1	450.04	428.08	391.23	335.12	MHz
	36 × 36-bit multiplier (5)	0	0	1	250.00	238.15	217.48	186.60	MHz
	36 × 36-bit multiplier (6)	0	0	1	410.17	390.01	356.12	305.06	MHz
	18-bit, four-tap FIR filter	0	0	1	410.17	390.01	356.12	305.06	MHz
Larger designs	8-bit, 16-tap parallel FIR filter	58	0	4	259.06	240.61	217.15	185.01	MHz
	8-bit, 1024-point, streaming, three multipliers and five adders FFT function	2976	22	9	398.72	364.03	355.23	306.37	MHz
	8-bit, 1024-point, streaming, four multipliers and two adders FFT function	2781	22	12	398.56	409.16	347.22	311.13	MHz
	8-bit, 1024-point, single output, one parallel FFT engine, burst, three multipliers and five adders FFT function	984	5	3	425.17	365.76	346.98	292.39	MHz
	8-bit, 1024-point, single output, one parallel FFT engine, burst, four multipliers and two adders FFT function	919	5	4	427.53	378.78	357.14	307.59	MHz

**Table 5–38. IOE Internal Timing Microparameters**

Symbol	Parameter	-3 Speed Grade (1)		-3 Speed Grade (2)		-4 Speed Grade		-5 Speed Grade		Unit
		Min (3)	Max	Min (3)	Max	Min (4)	Max	Min (3)	Max	
$t_{SU}$	IOE input and output register setup time before clock	122		128		140 140		163		ps
$t_H$	IOE input and output register hold time after clock	72		75		82 82		96		ps
$t_{CO}$	IOE input and output register clock-to-output delay	101	169	101	177	97 101	194	101	226	ps
$t_{PIN2COMBOUT\_R}$	Row input pin to IOE combinational output	410	760	410	798	391 410	873	410	1,018	ps
$t_{PIN2COMBOUT\_C}$	Column input pin to IOE combinational output	428	787	428	825	408 428	904	428	1,054	ps
$t_{COMBIN2PIN\_R}$	Row IOE data input to combinational output pin	1,101	2,026	1,101	2,127	1,049 1,101	2,329	1,101	2,439	ps
$t_{COMBIN2PIN\_C}$	Column IOE data input to combinational output pin	991	1,854	991	1,946	944 991	2,131	991	2,246	ps
$t_{CLR}$	Minimum clear pulse width	200		210		229 229		268		ps
$t_{PRE}$	Minimum preset pulse width	200		210		229 229		268		ps
$t_{CLKL}$	Minimum clock low time	600		630		690 690		804		ps
$t_{CLKH}$	Minimum clock high time	600		630		690 690		804		ps

**Notes to Table 5–38:**

- (1) These numbers apply to -3 speed grade EP2S15, EP2S30, EP2S60, and EP2S90 devices.
- (2) These numbers apply to -3 speed grade EP2S130 and EP2S180 devices.
- (3) For the -3 and -5 speed grades, the minimum timing is for the commercial temperature grade. Only -4 speed grade devices offer the industrial temperature grade.
- (4) For the -4 speed grade, the first number is the minimum timing parameter for industrial devices. The second number is the minimum timing parameter for commercial devices.

**Table 5–53. EP2S60 Column Pins Global Clock Timing Parameters**

Parameter	Minimum Timing		-3 Speed Grade	-4 Speed Grade	-5 Speed Grade	Unit
	Industrial	Commercial				
$t_{CIN}$	1.658	1.739	2.920	3.350	3.899	ns
$t_{COUT}$	1.501	1.574	2.678	3.072	3.575	ns
$t_{PLLCIN}$	0.06	0.057	0.278	0.304	0.355	ns
$t_{PLLCOUT}$	-0.097	-0.108	0.036	0.026	0.031	ns

**Table 5–54. EP2S60 Row Pins Regional Clock Timing Parameters**

Parameter	Minimum Timing		-3 Speed Grade	-4 Speed Grade	-5 Speed Grade	Unit
	Industrial	Commercial				
$t_{CIN}$	1.463	1.532	2.591	2.972	3.453	ns
$t_{COUT}$	1.468	1.537	2.587	2.968	3.448	ns
$t_{PLLCIN}$	-0.153	-0.167	-0.079	-0.099	-0.128	ns
$t_{PLLCOUT}$	-0.148	-0.162	-0.083	-0.103	-0.133	ns

**Table 5–55. EP2S60 Row Pins Global Clock Timing Parameters**

Parameter	Minimum Timing		-3 Speed Grade	-4 Speed Grade	-5 Speed Grade	Unit
	Industrial	Commercial				
$t_{CIN}$	1.439	1.508	2.562	2.940	3.421	ns
$t_{COUT}$	1.444	1.513	2.558	2.936	3.416	ns
$t_{PLLCIN}$	-0.161	-0.174	-0.083	-0.107	-0.126	ns
$t_{PLLCOUT}$	-0.156	-0.169	-0.087	-0.111	-0.131	ns

**Table 5–76. Stratix II I/O Output Delay for Row Pins (Part 2 of 3)**

I/O Standard	Drive Strength	Parameter	Minimum Timing		-3 Speed Grade (2)	-3 Speed Grade (3)	-4 Speed Grade	-5 Speed Grade	Unit
			Industrial	Commercial					
2.5 V	4 mA	t <sub>OP</sub>	1128	1183	2091	2194	2403	2523	ps
		t <sub>DIP</sub>	1086	1140	2036	2137	2340	2450	ps
	8 mA	t <sub>OP</sub>	1030	1080	1872	1964	2152	2265	ps
		t <sub>DIP</sub>	988	1037	1817	1907	2089	2192	ps
	12 mA (1)	t <sub>OP</sub>	1012	1061	1775	1862	2040	2151	ps
		t <sub>DIP</sub>	970	1018	1720	1805	1977	2078	ps
1.8 V	2 mA	t <sub>OP</sub>	1196	1253	2954	3100	3396	3542	ps
		t <sub>DIP</sub>	1154	1210	2899	3043	3333	3469	ps
	4 mA	t <sub>OP</sub>	1184	1242	2294	2407	2637	2763	ps
		t <sub>DIP</sub>	1142	1199	2239	2350	2574	2690	ps
	6 mA	t <sub>OP</sub>	1079	1131	2039	2140	2344	2462	ps
		t <sub>DIP</sub>	1037	1088	1984	2083	2281	2389	ps
	8 mA (1)	t <sub>OP</sub>	1049	1100	1942	2038	2232	2348	ps
		t <sub>DIP</sub>	1007	1057	1887	1981	2169	2275	ps
1.5 V	2 mA	t <sub>OP</sub>	1158	1213	2530	2655	2908	3041	ps
		t <sub>DIP</sub>	1116	1170	2475	2598	2845	2968	ps
	4 mA	t <sub>OP</sub>	1055	1106	2020	2120	2322	2440	ps
		t <sub>DIP</sub>	1013	1063	1965	2063	2259	2367	ps
SSTL-2 Class I	8 mA	t <sub>OP</sub>	1002	1050	1759	1846	2022	2104	ps
		t <sub>DIP</sub>	960	1007	1704	1789	1959	2031	ps
SSTL-2 Class II	16 mA (1)	t <sub>OP</sub>	947	992	1581	1659	1817	1897	ps
		t <sub>DIP</sub>	905	949	1526	1602	1754	1824	ps
SSTL-18 Class I	4 mA	t <sub>OP</sub>	990	1038	1709	1793	1964	2046	ps
		t <sub>DIP</sub>	948	995	1654	1736	1901	1973	ps
	6 mA	t <sub>OP</sub>	994	1042	1648	1729	1894	1975	ps
		t <sub>DIP</sub>	952	999	1593	1672	1831	1902	ps
	8 mA	t <sub>OP</sub>	970	1018	1633	1713	1877	1958	ps
		t <sub>DIP</sub>	928	975	1578	1656	1814	1885	ps
	10 mA (1)	t <sub>OP</sub>	974	1021	1615	1694	1856	1937	ps
		t <sub>DIP</sub>	932	978	1560	1637	1793	1864	ps

**Table 5–78. Maximum Output Toggle Rate on Stratix II Devices (Part 5 of 5)** *Note (1)*

I/O Standard	Drive Strength	Column I/O Pins (MHz)			Row I/O Pins (MHz)			Clock Outputs (MHz)		
		-3	-4	-5	-3	-4	-5	-3	-4	-5
1.2-V Differential HSTL	OCT 50 $\Omega$	280	-	-	-	-	-	280	-	-

**Notes to Table 5–78:**

- (1) The toggle rate applies to 0-pF output load for all I/O standards except for LVDS and HyperTransport technology on row I/O pins. For LVDS and HyperTransport technology on row I/O pins, the toggle rates apply to load from 0 to 5pF.
- (2) 1.2-V HSTL is only supported on column I/O pins in I/O banks 4, 7, and 8.
- (3) Differential HSTL and SSTL is only supported on column clock and DQS outputs.
- (4) HyperTransport technology is only supported on row I/O and row dedicated clock input pins.
- (5) LVPECL is only supported on column clock pins.
- (6) Refer to Tables 5–81 through 5–91 if using SERDES block. Use the toggle rate values from the clock output column for PLL output.

**Table 5–79. Maximum Output Clock Toggle Rate Derating Factors (Part 1 of 5)**

I/O Standard	Drive Strength	Maximum Output Clock Toggle Rate Derating Factors (ps/pF)								
		Column I/O Pins			Row I/O Pins			Dedicated Clock Outputs		
		-3	-4	-5	-3	-4	-5	-3	-4	-5
3.3-V LVTTTL	4 mA	478	510	510	478	510	510	466	510	510
	8 mA	260	333	333	260	333	333	291	333	333
	12 mA	213	247	247	213	247	247	211	247	247
	16 mA	136	197	197	-	-	-	166	197	197
	20 mA	138	187	187	-	-	-	154	187	187
	24 mA	134	177	177	-	-	-	143	177	177
3.3-V LVCMOS	4 mA	377	391	391	377	391	391	377	391	391
	8 mA	206	212	212	206	212	212	178	212	212
	12 mA	141	145	145	-	-	-	115	145	145
	16 mA	108	111	111	-	-	-	86	111	111
	20 mA	83	88	88	-	-	-	79	88	88
	24 mA	65	72	72	-	-	-	74	72	72
2.5-V LVTTTL/LVCMOS	4 mA	387	427	427	387	427	427	391	427	427
	8 mA	163	224	224	163	224	224	170	224	224
	12 mA	142	203	203	142	203	203	152	203	203
	16 mA	120	182	182	-	-	-	134	182	182